Authors

Euval S. Barrekette

A.B., 1952, Columbia College. B.S. in Civil Engineering, 1953, Columbia University; M.S. in Flight Structure, 1956; Ph.D. Engineering Mechanics, 1959. Guggenheim Fellow, Columbia University, 1955-57; Assistant Professor of Civil Engineering, 1959-60; later Adjunct Associate Professor of Civil Engineering. In 1960 became member of the research staff at the IBM Thomas J. Watson Research Center, where he was Technical Assistant to the Director of Research and Manager of Special Technical Studies. He is currently Manager of Exploratory Systems. Member of the New York State Society of Professional Engineers, the American Institute of Aeronautics and Astronautics, American Society of Civil Engineers, Phi Beta Kappa, Tau Beta Pi, and Sigma Xi.

Robert L. Christensen

A.B., 1950; M.A., 1954; Ph.D. in Physics, 1957, all from Princeton University. Research in neutron physics, Brookhaven National Laboratory, 1953. Research Assistant, Princeton University, 1957 and 1958. Joined IBM Research in Poughkeepsie in 1958, working in electron, vacuum, and optical physics. Most recently, Applications Engineering Manager, IBM Systems Development Division Laboratory, Kingston.

Edward B. Eichelberger

B. S. in Electrical Engineering, 1956, Lehigh University; M. A. and Ph.D. in Electrical Engineering, 1963, Princeton. Joined IBM in 1956 and worked in solid state circuit design at the Endicott Product Development Laboratory. In 1959, he began graduate study at Princeton University under the IBM Resident Graduate Study Program. While at Princeton, he worked in the field of switching theory. Presently is Manager of the Scientific Computation Laboratory at the Systems Development Division Laboratory in Endicott. Member of IEEE and ACM.

Davis S. Fields, Jr.

B.S. in Physics, 1950, University of Kentucky; M.S., 1954, and Sc.D., 1957, in Metallurgy, M.I.T. Associated with Metal Processing Branch, Watertown Arsenal Laboratories, 1951 and 1952; Physical Metallurgy Division, Alcoa Research Laboratories, 1957 to 1960; Metallurgical Engineering Faculty, University of Kentucky, 1960 to 1962. Joined IBM in 1962, and is now Advisory Metallurgist, Exploratory Engineering Department, Office Products Division, Lexington, Kentucky. Is a member of the American Society for Metals, American Institute of Mining, Metallurgical, and Petroleum Engineers, American Society for Testing and Materials, and Sigma Xi.

Donald P. Gaver, Jr.

S.B. in Mathematics, 1950, and S.M. in Mathematics, 1951, M.I.T.; Ph.D. in Mathematics, 1956, Princeton University. Visiting Associate Professor of Statistics, Stanford University, 1961 to 1962. Associate Professor, Mathematics and Industrial Administration, Carnegie Institute of Technology. Advisory Mathematician, Westinghouse Research Laboratories. Research interests: application of probability theory and statistics. Member, Institute of Mathematical Statistics, American Statistical Association, Operations Research Society of America, and Institute of Management Sciences.

Friedrich R. Hertrich

M.S. in Mechanical Engineering, 1957, Technische Hochschule Munich; Ph.D., 1960, Bergakademie Clausthal (Germany). Worked with Rheinstahl Huettenwerke AG., Gelsenkirchen, Germany, as Development Engineer and Consultant, 1957 to 1961. Joined IBM in 1961 at the General Products Division Laboratory, San Jose, where he worked on the development of mass storage devices. Presently, Advisory Engineer in the Random Access Memory Program, Systems Development Division, San Jose.

Herbert J. Kump

B.S. in Physics, 1951, Pennsylvania State University; M.E.E., 1960, Syracuse University. Joined IBM at Endicott, New York in 1955 and worked in the magnetic recording and storage fields. Was engaged in the development of a magnetic thin film memory in the Components Division at Poughkeepsie. Presently engaged in the development of advanced magnetic memory systems for the Systems Development Division in Poughkeepsie. Received an Outstanding Invention Award for contributions in magnetic recording in 1963 and an Invention Achievement Award in 1964.

Charles LeMéhauté

B.S., 1947, University of Rennes; Diploma, 1952, Ecole Nationale Superieure d'Ingenieurs, Nantes; Institut Superieur des Materiaux, Paris, 1954. Joined IBM France in 1956. Manager of Physics and Chemistry Laboratory in the IBM Development Engineering Center, La Gaude, France. Member of the French Metallurgical Society, the French Physical Society, and the C.I.T.C.E. (International Society for Electrochemistry).

Simon Middelhoek

M.S. in Physical Engineering, 1956, Technical University of Delft, Holland; Ph.D. in Physics, 1961, University of Amsterdam. Assistant in Physics, 1953-1956. Joined IBM in 1956 as Physicist in the Research Laboratory, Zurich. His

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present field of interest is ferromagnetic domains in thin Ni-Fe films. Member of the Dutch Physical Society, the Royal Institute of Engineers, and the German Study Group on Ferromagnetism.

Edouard Y. Rocher

Ecole Centrale des Arts et Manufactures, Paris, 1956; Dr. Ing., 1963, Technische Hochschule, Darmstadt (Germany). Joined IBM France Development Engineering Center, La Gaude, in 1961.

Paul M. Thrasher

B.S. in Physics, 1941, University of the South; B.S.E.E., 1943, Lehigh University. Joined IBM in 1960. Experience includes digital and sampled data processing and signal analysis. Is presently working on multiplexing and switching

techniques as an Advisory Engineer in the Communications Systems Department of the Federal Systems Division at Bethesda.

Hans J. Zweig

B.A. in Mathematics, 1949, University of Rochester; M.S. in Philosophy, 1951, Brown University; Ph.D. in Statistics, 1963, Stanford University. Worked in the Physics Research Division at Eastman Kodak 1951 to 1962; held a University Fellowship in Statistics at Columbia University 1959 and 1960; received the Journal Award for the best paper published during 1961 in *Photographic Science and Engineering*. Since joining IBM in 1963, he has been working on statistical aspects of photodetection in the Optics Department, Advanced Technology, Systems Development Division, San Jose. He is a member of the Optical Society of America, the Society of Photographic Scientists and Engineers, the Institute of Mathematical Statistics, and Sigma Xi.

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